

## Description

# METHOD OF SOLDERING SEMICONDUCTOR PART AND MOUNTED STRUCTURE OF SEMICONDUCTOR PART

## BACKGROUND OF THE INVENTION

[0001] [Field of the Invention]

[0002] The present invention relates to a method of soldering a semiconductor part and a mounted structure of a semiconductor part and, more particularly, to a method of soldering a semiconductor part which cannot be passed through a reflow furnace because of a low guaranteed heat resistant temperature onto a small land and a mounted structure of a semiconductor part which is formed by this method.

[0003] [Description of the Related Art]

[0004] In general, when a part such as a semiconductor package is soldered to a circuit board, as shown in FIG. 3, a semiconductor part 1 is disposed on a land 4 for soldering and

a cream solder 3 is printed on this land 4. At this time, the cream solder 3 is printed so that an electrode 2 of the semiconductor part 1 is electrically connected to the land 4. And the circuit board on which the semiconductor part 1 is thus mounted is passed through a reflow furnace to cause the cream solder 3 to be melted in order to perform soldering (refer to, for example, Patent Document 1).

[Patent Document 1] Japanese Patent Laid-Open No.  
10-41465

[0005] In such a reflow fabrication process, to avoid a thermal fracture of the semiconductor part 1, it is necessary that the surface temperature of this semiconductor part 1 be not more than a guaranteed heat resistant temperature. For this reason, the reflow fabrication process had the disadvantage that much ancillary work has to be performed before and after reflow, for example, it is necessary to stick a heat resistant film to the semiconductor part 1 or apply resin to the semiconductor part 1 before the circuit board is passed through the reflow furnace, it is necessary to peel the heat resistant film after the circuit board is passed through the reflow furnace, and the like.

[0006] Incidentally, a thermal fracture of the semiconductor part 1 can be avoided by lowering the heating temperature in

the reflow furnace to not more than a guaranteed heat resistant temperature of the semiconductor part 1. However, in order to ensure that the cream solder 3 is positively melted, it is necessary that the temperature of the land 4 be not less than a melting temperature of the solder.

Therefore, in order to eliminate insufficient heating of the cream solder, there has been proposed a method by which a through via hole which is connected to an inner layer pattern or an outer layer pattern of a circuit board is connected directly to a land and the heat of a reflow furnace is collected to the land via the through via hole (refer to, for example, Patent Document 2). [Patent Document 2]

Japanese Patent Laid-Open No. 10-229273

- [0007] Incidentally, in some package structures, there are packages incapable of being passed through the reflow furnace because of their low guaranteed heat resistant temperatures. In this case, a soldering fabrication process by the local heating method is effective. As such processes, there is a hand soldering fabrication process which involves performing manual soldering using a wire solder by means of a soldering iron and a laser beam fabrication process which involves performing soldering by irradiating a cream solder with focused laser beams (for example,

refer to Patent Documents 3 and 4). [Patent Document 3] Japanese Patent Laid-Open No. 5-69182; [Patent Document 4] Japanese Patent Laid-Open No. 2000-299239.

- [0008] However, the hand soldering fabrication process has the disadvantage that not only man-hours increase much, but also the reliability of soldering is apt to generate variations according to the ability of workers. On the other hand, in the case of the laser beam fabrication process, man-hours are relatively small and the reliability of soldering scarcely generates variations according to the ability of workers. Therefore, in quite a number of cases, soldering has been performed by the laser beam fabrication method.
- [0009] In recent years, however, to meet requirements for high functional design and small size and light weight design, progress has been made in high density design of semiconductor parts and there have been an increasing number of cases where the size of lands has to be reduced because the space of a circuit substrate decreases. When a land becomes small, it becomes impossible to ensure a sufficient land space around a semiconductor part to be mounted and only the area almost on the backside of the semiconductor part can be soldered.

## SUMMARY OF THE INVENTION

- [0010] The present invention is made in view of this situation and has as its object to ensure that in a case where a semiconductor part incapable of being passed through a reflow furnace because of a low guaranteed heat resistant temperature is to be mounted on a circuit substrate in high density, the semiconductor part can be positively soldered even onto a land which is so small that a solder can be printed only in a back side portion of the semiconductor part.
- [0011] To solve the above-described problem, in the present invention, a semiconductor part in which a metal terminal is formed on its back surface and side surface is mounted on a land so that only the back surface portion of the metal terminal is in contact with a cream solder and the land and the semiconductor are soldered together by irradiating the side surface portion of the metal terminal with laser beams.
- [0012] According to the present invention configured as described above, due to thermal conduction from a side surface portion of a metal terminal to a back surface portion of the metal terminal, the back surface portion of the metal terminal is heated and a cream solder in contact

with the back surface portion of the metal terminal is melted, with the result that soldering is performed. As a result of this, in a case where a semiconductor part incapable of being passed through a reflow furnace because of a low guaranteed heat resistant temperature is to be mounted on a circuit substrate in high density, the semiconductor part can be positively soldered even onto a land which is so small that a solder can be printed only in a backside portion of the semiconductor part.

## BRIEF DESCRIPTION OF THE DRAWINGS

- [0013] FIG. 1 is a flow chart showing an outline of a method of soldering a semiconductor part according to this embodiment;
- [0014] FIG. 2 is a drawing to show a mounted structure of a semiconductor part according to this embodiment; and
- [0015] FIG. 3 is a drawing to explain a conventional method of soldering a semiconductor.

## DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

- [0016] An embodiment of the present invention will be described on the basis of the drawings. FIG. 1 is a flow chart showing an outline of a method of soldering a semiconductor part according to this embodiment. FIG. 2 is a drawing to

show a mounted structure of a semiconductor part according to this embodiment.

- [0017] As shown in FIG. 1 and FIG. 2, first, a cream solder 3 is printed on a land 4 of a circuit substrate 5 (Step S1), and the circuit substrate 5 is placed on a preheat stage 6. Next, a semiconductor part 1 in which a metal terminal 2 is formed on its back surface and side surface is mounted on the land 4 on which the cream solder 3 is printed. At this time, the semiconductor part 1 is mounted on the land 4 so that almost all area of the land 4 is opposed to the mounting surface (back surface) of the semiconductor part 1 and only the back surface portion of the metal terminal 2 is in contact with the cream solder 3.
- [0018] And, by use of a laser diode (LD) 7, for example, the solder joining of the semiconductor part 1 and the land 4 is performed by irradiating the side surface portion of the metal terminal 2 with laser beams (Step S3). That is, when the side portion of the metal terminal 2 is irradiated with laser beams, the back surface portion of the metal terminal 2 is heated by thermal conduction and the cream solder 3 in contact with the back surface portion is melted, whereby soldering is performed.
- [0019] In this Step S3, it is desirable to supply cold air to a sur-

face of the semiconductor part 1 on which the metal terminal 2 is not formed (for example, the top surface). For example, when the guaranteed heat resistant temperature of the semiconductor part 1 is very low, a thermal fracture may be caused by the heat which conducts from the metal terminal 2 to a package. Therefore, by supplying cold air to the package, it is possible to perform normal soldering by overheating the metal terminal 2 while keeping the package at a temperature of not more than the guaranteed heat resistant temperature.

- [0020] Furthermore, it is desirable to set temperature conditions so that a difference between the heating temperature near the metal terminal 2 which is irradiated with laser beams and the package temperature near the surface to which cold air is supplied becomes within a prescribed temperature. This is because an extreme temperature difference might break the package (for example, a ceramic package).
- [0021] As described above in detail, according to this embodiment, the semiconductor part 1 in which the metal terminal 2 is formed on its back surface and side surface is mounted so that only the back surface portion of the metal terminal 2 is in contact with the cream solder 3 and

the soldering of the semiconductor part 1 is performed by irradiating a side surface portion of the metal terminal 2 with laser beams. Therefore, in a case where a semiconductor part 1 incapable of being passed through a reflow furnace because of a low guaranteed heat resistant temperature is to be mounted on the circuit substrate 5 in high density, it is ensured that the semiconductor part 1 can be positively soldered even onto a land 4 which is so small that the cream solder 3 can be printed only in a back side portion of the semiconductor part 1.

[0022] Incidentally, the above-described embodiment is only an example of embodiment in carrying out the present invention and it should be noted that the technical scope of the invention is not construed in a manner limited by this embodiment. That is, the present invention can be carried out in various forms without departing from the spirit of the invention or its principal features.

## **INDUSTRIAL APPLICABILITY**

[0023] The present invention is useful in high density mounting technology for soldering a semiconductor part incapable of being passed through a reflow furnace because of a low guaranteed heat resistant temperature onto a land which is so small that it allows a solder to be printed to only a

**back side portion of the semiconductor part.**